



Single P-Channel Logic Level Enhancement Mode Field Effect Transistor

▪ Product Summary:

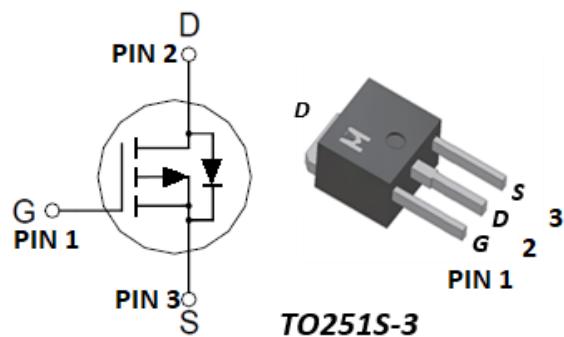
| | |
|---|-------|
| | P-CH |
| BV _{DSS} | -60V |
| R _{DSON} (MAX.) @ V _{GS} =-10V | 90mΩ |
| R _{DSON} (MAX.) @ V _{GS} =-4.5V | 140mΩ |
| I _D @ T _C =25°C | -15A |
| I _D @ T _A =25°C | -3.8A |

Single P Channel MOSFET

UIS, Rg 100% Tested

RoHS & Halogen Free & TSCA Compliant

▪ Pin Description:



▪ ABSOLUTE MAXIMUM RATINGS (T_C = 25 °C Unless Otherwise Noted)

| PARAMETERS/TEST CONDITIONS | | SYMBOL | LIMITS | UNIT |
|--|-------------------------|-----------------------------------|------------|------|
| Gate-Source Voltage | | V _{GS} | ±20 | V |
| Continuous Drain Current ¹ | T _C = 25 °C | I _D | -15 | A |
| | T _C = 100 °C | | -9.5 | |
| Continuous Drain Current ¹ | T _A = 25 °C | I _D | -3.8 | |
| | T _A = 70 °C | | -3.0 | |
| Pulsed Drain Current ¹ | | I _{DM} | -33 | |
| Avalanche Current ^{1,4} | | I _{AS} | -30 | |
| Avalanche Energy ¹ | L = 0.1mH | EAS | 45 | mJ |
| Repetitive Avalanche Energy ² | L = 0.05mH | EAR | 22.5 | |
| Power Dissipation ¹ | T _C = 25 °C | P _D | 40 | W |
| | T _C = 100 °C | | 16 | |
| Power Dissipation ¹ | T _A = 25 °C | P _D | 2.6 | W |
| | T _A = 70 °C | | 1.6 | |
| Operating Junction & Storage Temperature Range | | T _j , T _{stg} | -55 to 150 | °C |

▪ 100% UIS testing in condition of VD=40V, L=0.1mH, VG=10V, IL=18A, RG=25Ω, Rated VDS=60V P-CH

▪ THERMAL RESISTANCE RATINGS

| THERMAL RESISTANCE | | SYMBOL | TYPICAL | MAXIMUM | UNIT |
|----------------------------------|--------------|------------------|---------|---------|--------|
| Junction-to-Case | | R _{θJC} | | 3.1 | °C / W |
| Junction-to-Ambient ³ | t≤10s | R _{θJA} | | 15 | |
| | Steady-State | R _{θJA} | | 49 | |

¹Pulse width limited by maximum junction temperature.

²Duty cycle < 1%

³The value of R_{θJA} is measured with the device mounted on 1in² FR-4 board with 2oz. Copper, in a still air environment with T_A=25°C.

⁴Guarantee by Engineering test



▪ ELECTRICAL CHARACTERISTICS ($T_J = 25^\circ\text{C}$, Unless Otherwise Noted)

| PARAMETER | SYMBOL | TEST CONDITIONS | LIMITS | | | UNIT |
|---|-------------------------------------|---|--------|------|-----------|------------------|
| | | | MIN | TYP | MAX | |
| STATIC | | | | | | |
| Drain-Source Breakdown Voltage ⁴ | $V_{(\text{BR})\text{DSS}}$ | $V_{\text{GS}} = 0\text{V}, I_D = -250\mu\text{A}$ | -60 | | | V |
| Gate Threshold Voltage ⁴ | $V_{\text{GS}(\text{th})}$ | $V_{\text{DS}} = V_{\text{GS}}, I_D = -250\mu\text{A}$ | -1.2 | -1.5 | -2.5 | |
| Gate-Body Leakage ⁴ | I_{GSS} | $V_{\text{DS}} = 0\text{V}, V_{\text{GS}} = \pm 20\text{V}$ | | | ± 100 | nA |
| Zero Gate Voltage Drain Current ⁴ | I_{DSS} | $V_{\text{DS}} = -60\text{V}, V_{\text{GS}} = 0\text{V}$ | | | -1 | μA |
| | | $V_{\text{DS}} = -60\text{V}, V_{\text{GS}} = 0\text{V}, T_J = 125^\circ\text{C}$ | | | -25 | |
| On-State Drain Current ¹ | $I_{\text{D}(\text{ON})}$ | $V_{\text{DS}} = -10\text{V}, V_{\text{GS}} = -10\text{V}$ | -15 | | | A |
| Drain-Source On-State Resistance ^{1,4} | $R_{\text{DS}(\text{ON})}$ | $V_{\text{GS}} = -10\text{V}, I_D = -10\text{A}$ | | 60 | 90 | $\text{m}\Omega$ |
| | | $V_{\text{GS}} = -4.5\text{V}, I_D = -8\text{A}$ | | 70 | 140 | |
| Forward Transconductance ¹ | g_{fs} | $V_{\text{DS}} = -5\text{V}, I_D = -4\text{A}$ | | 18 | | S |
| DYNAMIC | | | | | | |
| Input Capacitance ⁵ | C_{iss} | $V_{\text{GS}} = 0\text{V}, V_{\text{DS}} = -30\text{V}, f = 1\text{MHz}$ | | 1320 | | pF |
| Output Capacitance ⁵ | C_{oss} | | | 80 | | |
| Reverse Transfer Capacitance ⁵ | C_{rss} | | | 60 | | |
| Gate Resistance ^{4,5} | R_g | $f = 1\text{MHz}$ | | 6.1 | | Ω |
| Total Gate Charge ^{1,2,5} | $Q_g(V_{\text{GS}} = -10\text{V})$ | $V_{\text{DS}} = -30\text{V}, V_{\text{GS}} = -10\text{V}, I_D = -10\text{A}$ | | 33 | | nC |
| | $Q_g(V_{\text{GS}} = -4.5\text{V})$ | | | 15 | | |
| Gate-Source Charge ^{1,2,5} | Q_{gs} | | | 4.7 | | |
| Gate-Drain Charge ^{1,2,5} | Q_{gd} | | | 5.5 | | |
| Turn-On Delay Time ^{1,2,5} | $t_{\text{d}(\text{on})}$ | | | 6.3 | | nS |
| Rise Time ^{1,2,5} | t_r | $V_{\text{DS}} = -30\text{V}, V_{\text{GS}} = -10\text{V}, I_D = -5\text{A}, R_g = 6\Omega$ | | 11 | | |
| Turn-Off Delay Time ^{1,2,5} | $t_{\text{d}(\text{off})}$ | | | 75 | | |
| Fall Time ^{1,2,5} | t_f | | | 31 | | |
| SOURCE-DRAIN DIODE RATINGS AND CHARACTERISTICS | | | | | | |
| Continuous Current | I_s | | | | -15 | A |
| Pulsed Current ³ | I_{SM} | | | | -33 | |
| Forward Voltage ^{1,4} | V_{SD} | $I_F = -10\text{A}, V_{\text{GS}} = 0\text{V}$ | | | -1.2 | V |
| Reverse Recovery Time ⁵ | t_{rr} | $I_F = -10\text{A}, dI_F/dt = 100\text{A}/\mu\text{s}$ | | 19 | | nS |
| Peak Reverse Recovery Current ⁵ | $I_{\text{RM}(\text{REC})}$ | | | 1.8 | | A |
| Reverse Recovery Charge ⁵ | Q_{rr} | | | 16 | | nC |

¹Pulse test : Pulse Width ≤ 300 usec, Duty Cycle $\leq 2\%$.

²Independent of operating temperature.

³Pulse width limited by maximum junction temperature.

⁴Guarantee by FT test Item

⁵Guarantee by Engineering test

EMC will review datasheet by quarter, and update new version.



-TYPICAL CHARACTERISTICS

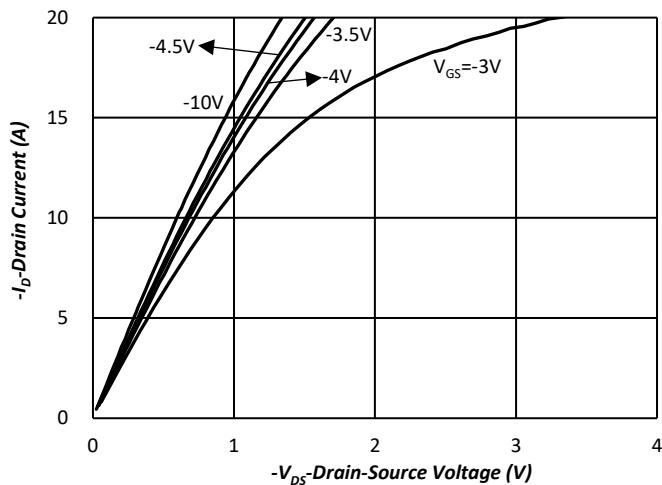


Fig.1 Typical Output Characteristics

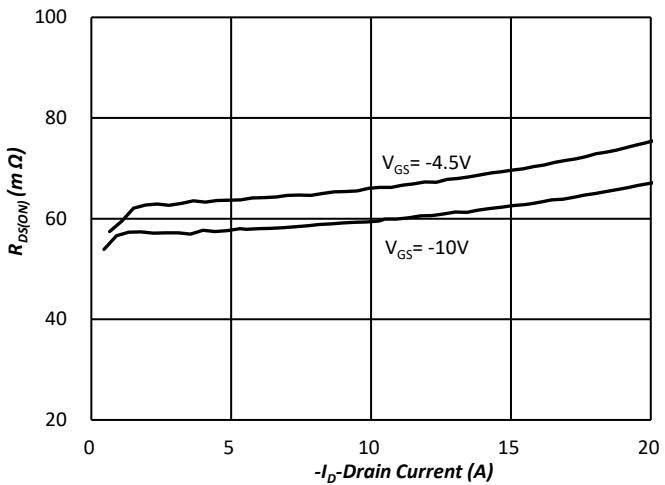


Fig.2 On-Resistance Variation with Drain Current and Gate Voltage

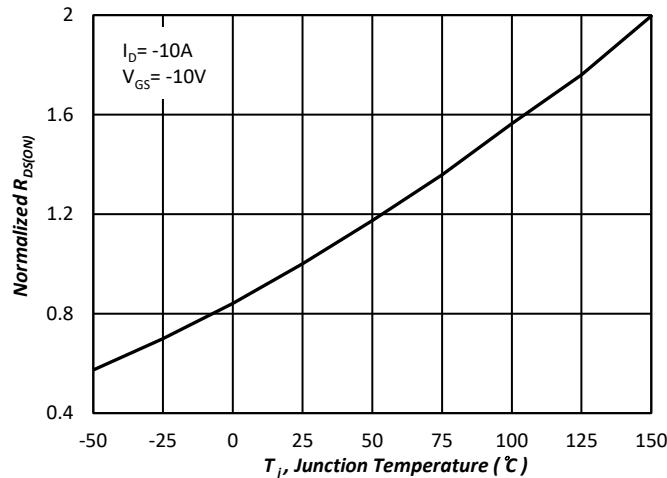


Fig.3 Normalized On-Resistance v.s. Junction Temperature

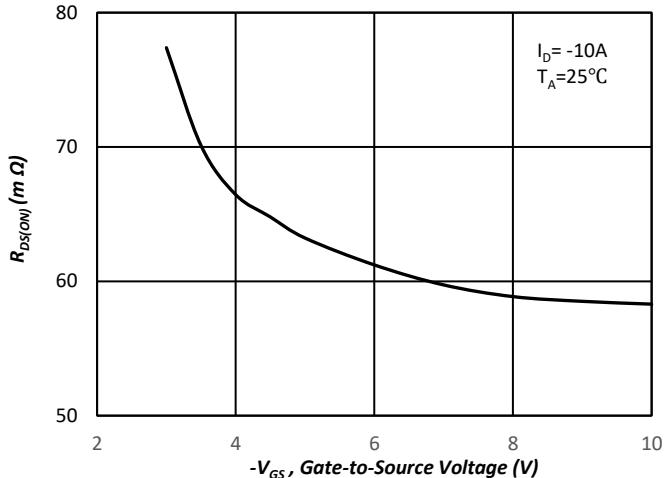


Fig.4 On-Resistance v.s. Gate Voltage

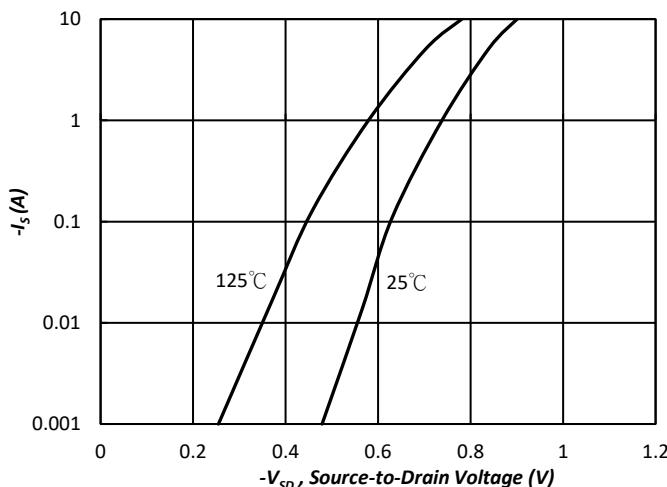


Fig.5 Forward Characteristic of Reverse Diode

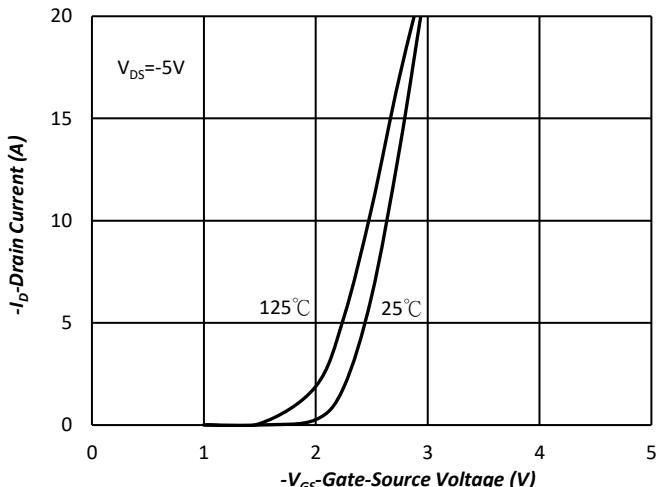
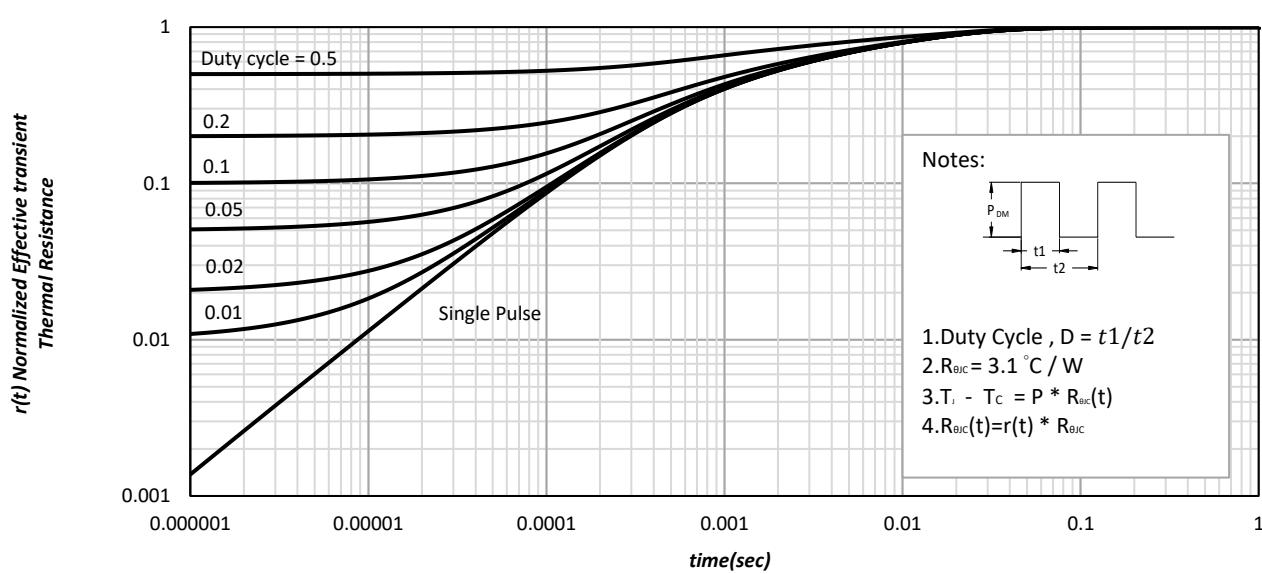
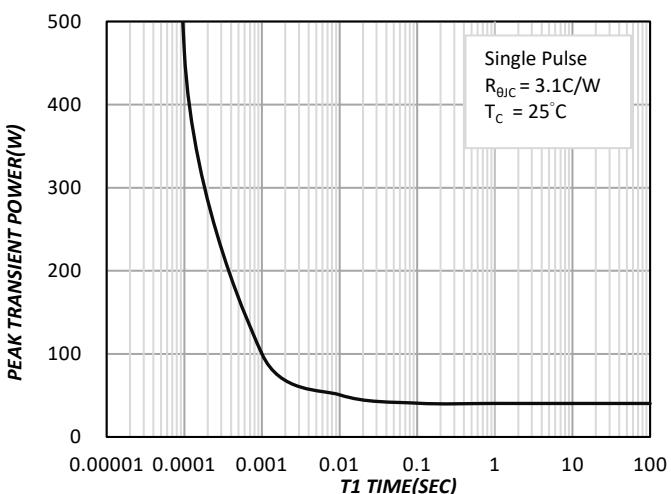
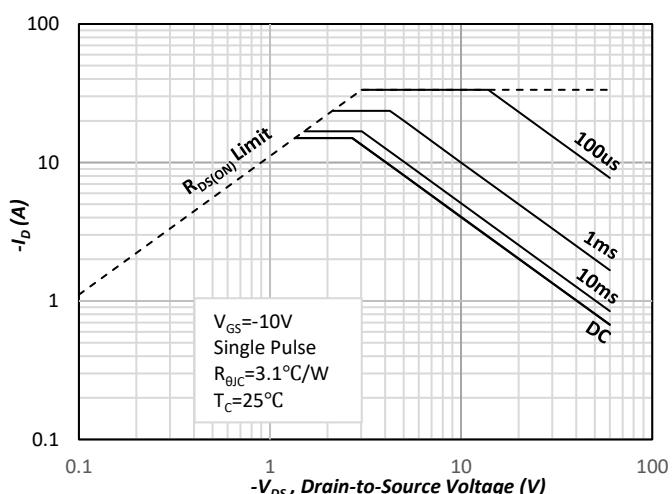
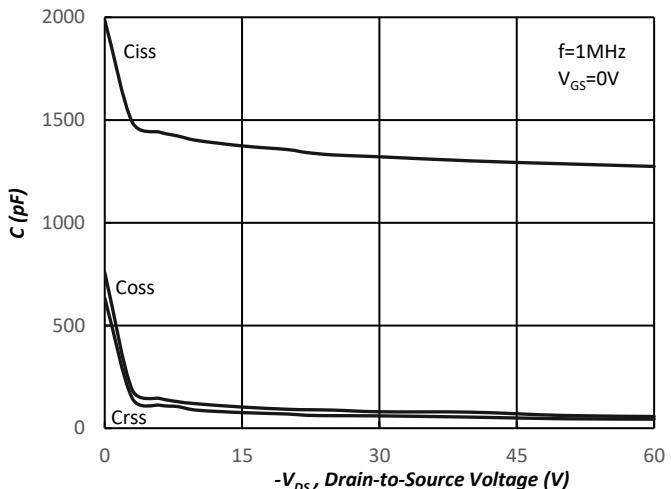
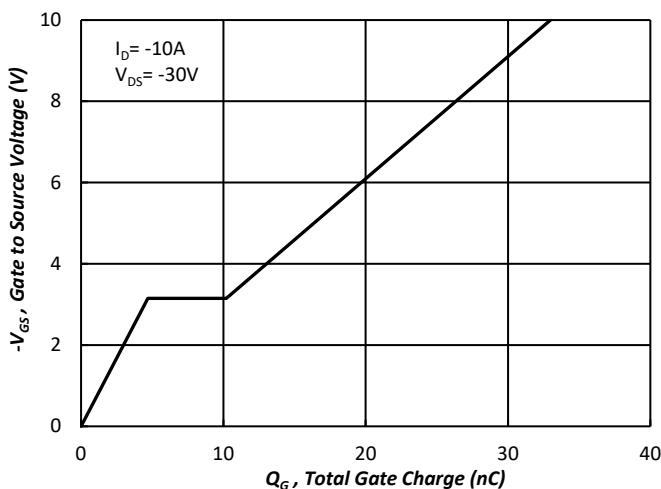
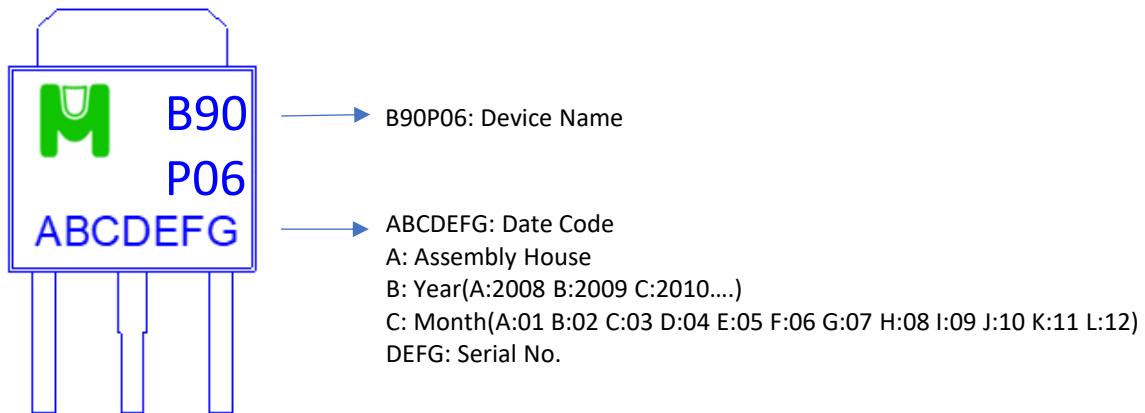


Fig.6 Transfer Characteristics

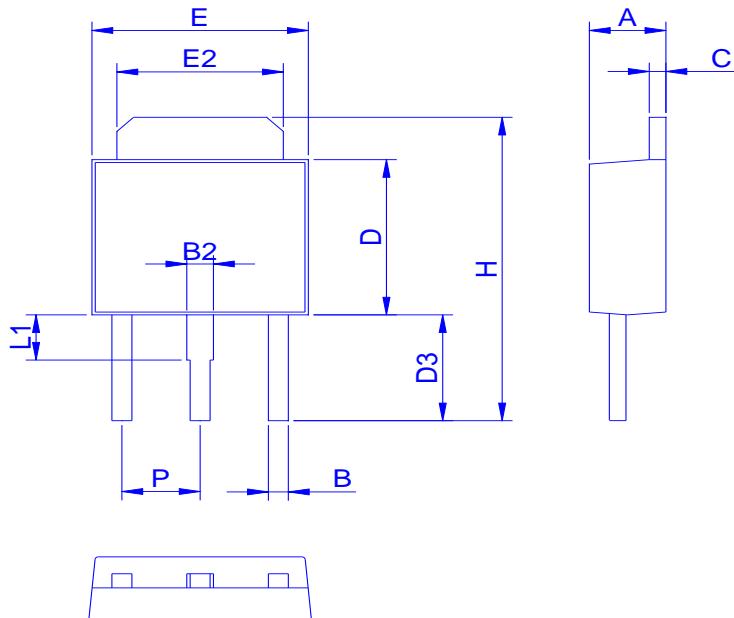


Ordering & Marking Information:

Device Name: EMB90P06CS for TO251S-3



Outline Drawing



| Dimension | A | B | B2 | C | D | D3 | E | E2 | H | L1 | P |
|-----------|------|------|------|------|------|------|------|------|-------|------|------|
| Min. | 2.20 | 0.64 | 0.66 | 0.46 | 6.00 | 3.30 | 6.40 | 5.10 | 10.40 | 0.97 | 2.19 |
| Typ. | 2.30 | 0.76 | 0.79 | 0.50 | 6.10 | 3.50 | 6.60 | 5.28 | 10.70 | 1.10 | 2.29 |
| Max. | 2.40 | 0.88 | 1.14 | 0.60 | 6.22 | 4.28 | 6.73 | 5.46 | 11.45 | 1.27 | 2.39 |



◆ Tape&Reel Information: 75pcs/Reel

